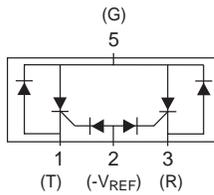


Battrax Dual Negative SLIC Protector



This solid state *Battrax* protection device is referenced to a negative voltage source. Its dual-chip package also includes internal diodes for transient protection from positive surge events.

For a diagram of a *Battrax* application, see Figure 3.36.

Electrical Parameters

Part Number *	V _{DRM} Volts	V _S Volts	V _T Volts	V _F Volts	I _{DRM} μAmps	I _{GT} mAmps	I _T Amps	I _H mAmps	C _O pF
B1101U ₋	-V _{REF} + -1.2V	-V _{REF} + -10V	4	5	5	100	2.2	100	50
B1161U ₋	-V _{REF} + -1.2V	-V _{REF} + -10V	4	5	5	100	2.2	160	50
B1201U ₋	-V _{REF} + -1.2V	-V _{REF} + -10V	4	5	5	100	2.2	200	50

* For individual "UA" and "UC" surge ratings, see table below.

General Notes:

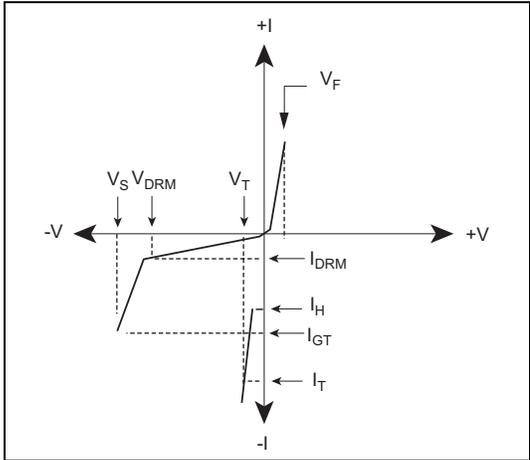
- All measurements are made at an ambient temperature of 25 °C. I_{PP} applies to -40 °C through +85 °C temperature range.
- I_{PP} is a repetitive surge rating and is guaranteed for the life of the product.
- I_{PP} ratings assume a V_{REF} = -48 V.
- V_{DRM} is measured at I_{DRM}.
- V_S is measured at 100 V/μs.
- Off-state capacitance (C_O) is measured at 1 MHz with a 2 V bias and is a typical value. "UC" product is approximately 2x the listed value.
- V_{REF} maximum value for the B1101, B1161, and/or B1201 is -200 V.

Surge Ratings

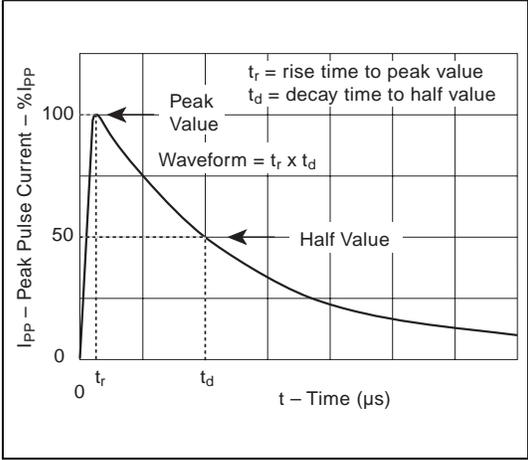
Series	I _{PP} 2x10 μs Amps	I _{PP} 8x20 μs Amps	I _{PP} 10x160 μs Amps	I _{PP} 10x560 μs Amps	I _{PP} 10x1000 μs Amps	I _{TSM} 60 Hz Amps	di/dt Amps/μs
A	150	150	90	50	45	20	500
C	500	400	200	120	100	50	500

Thermal Considerations

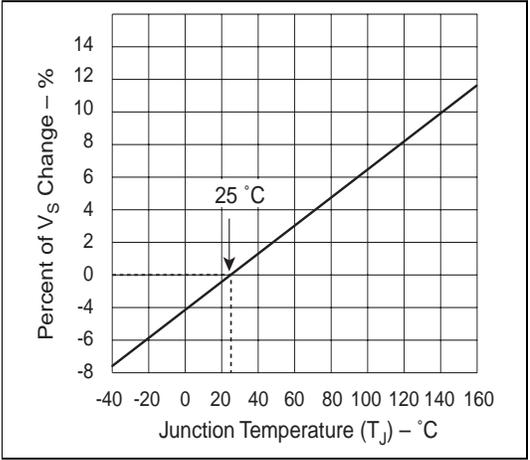
Package	Symbol	Parameter	Value	Unit
	T_J	Operating Junction Temperature Range	-40 to +125	$^{\circ}\text{C}$
	T_S	Storage Temperature Range	-65 to +150	$^{\circ}\text{C}$
	$R_{\theta JA}$	Thermal Resistance: Junction to Ambient	60	$^{\circ}\text{C/W}$



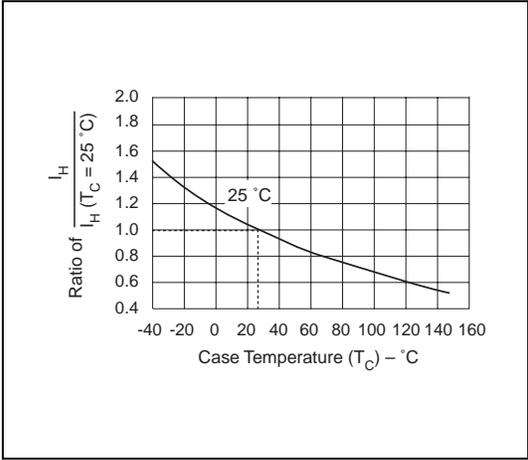
V-I Characteristics



$t_r \times t_d$ Pulse Wave-form



Normalized V_S Change versus Junction Temperature



Normalized DC Holding Current versus Case Temperature

Data Sheets